**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

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| Applicant: | **Ching-Wei LIN** | Filed: | **10/3/2003** |
| Appl. No.: | **10/678,908** | Examiner: | **EVERHART, CARIDAD** |
| Conf. No.: | **2225** | Art Unit: | **2891** |

Title: **PROCESS FOR PASSIVATING POLYSILICON AND PROCESS FOR FABRICATING POLYSILICON THIN FILM TRANSISTOR**

Date: **December 22, 2006**

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

**AMENDMENT**

Sir:

The Office Action mailed on **September 25, 2006** has been carefully considered. In response thereto, the Applicant respectfully requests entry of the amendments and consideration of the remarks as set forth herein below:

**Amendments to the Claims** are reflected in the listing of claims that begins on page 2 of this paper.

**Remarks** begin on page 5 of this paper.

All amendments and remarks made herein are without prejudice.